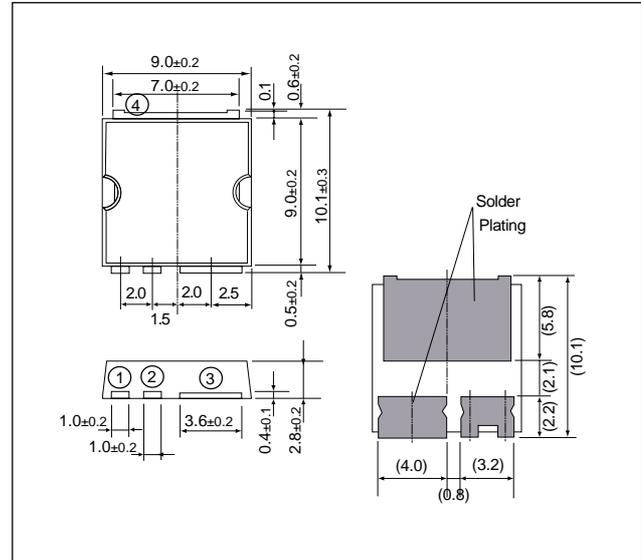


MS808C06 (30A)

(60V / 30A)

SCHOTTKY BARRIER DIODE

■ Outline drawings, mm



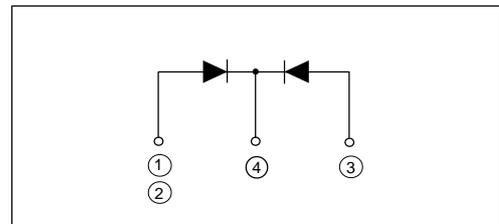
■ Features

- Low V_F
- Super high speed switching
- High reliability by planer design

■ Applications

- High speed power switching

■ Connection diagram



■ Maximum ratings and characteristics

- Absolute maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}		60	V
Non-repetitive peak reverse voltage	V_{RSM}	$t_w=500\text{ns}$, $\text{duty}=1/40$	60	V
Average output current	I_o	Square wave, $\text{duty}=1/2$ $T_c=118^\circ\text{C}$	30*	A
Surge current	I_{FSM}	Sine wave 10ms	200	A
Operating junction temperature	T_j		-40 to +150	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to +150	$^\circ\text{C}$

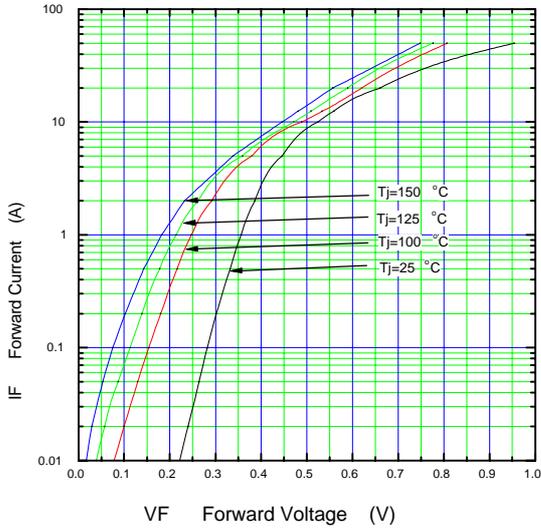
* Average forward current of centertap full wave connection

- Electrical characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

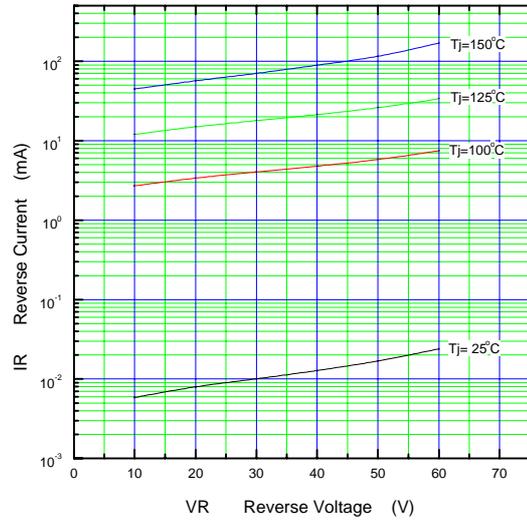
Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V_{FM}	$I_{FM}=12.5\text{A}$	0.58	V
Reverse current	I_{RRM}	$V_R=V_{RRM}$	20	mA
Thermal resistance	$R_{th(j-c)}$	Junction to case	1.2	$^\circ\text{C}/\text{W}$

Characteristics

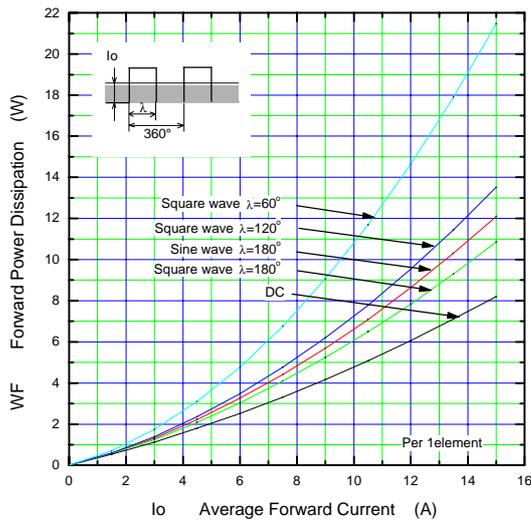
Forward Characteristic (typ.)



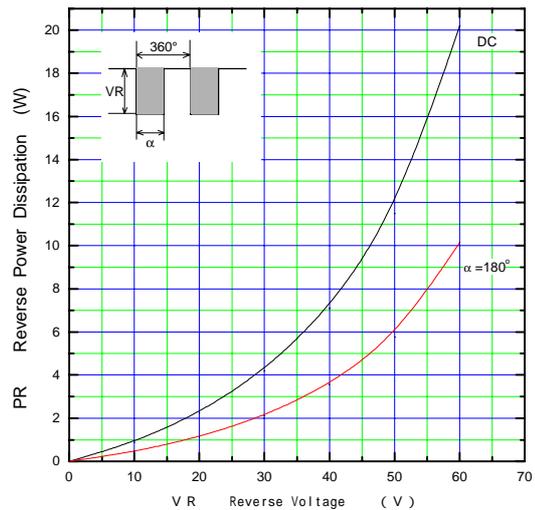
Reverse Characteristic (typ.)



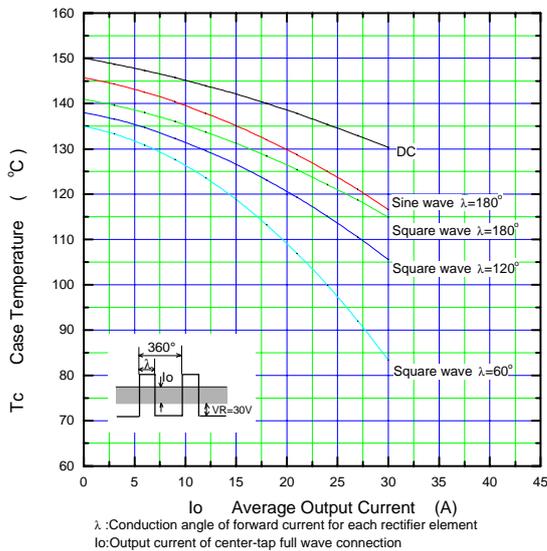
Forward Power Dissipation



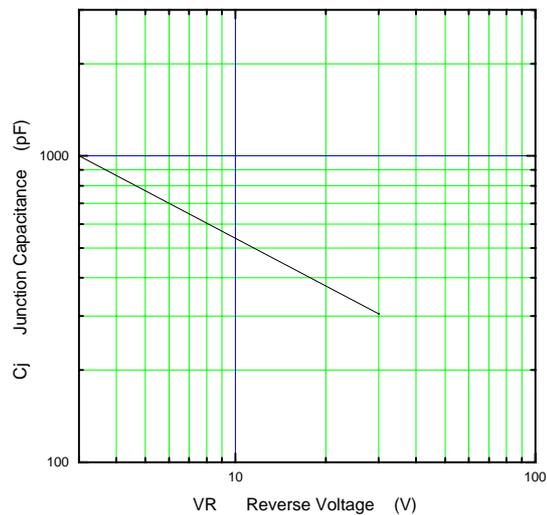
Reverse Power Dissipation



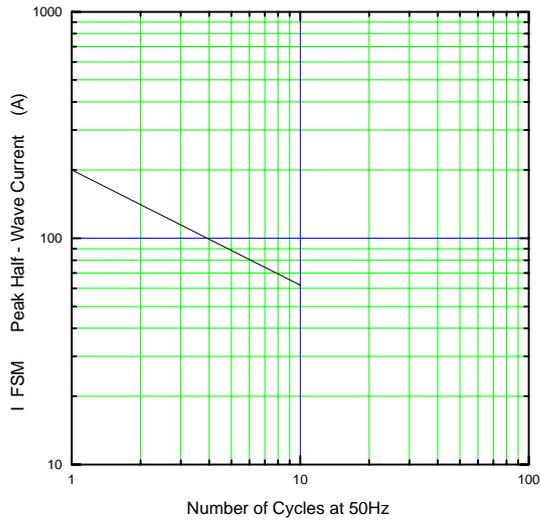
Current Derating (I_o-T_c)



Junction Capacitance Characteristic (typ.)



Surge Capability



Transient Thermal Impedance

